

SST-10-UV

Surface Mount UV LED



Table of Contents

Technology Overview 2
Binning Structure3
Ordering Information4
Ordering Bin Kits 4
Optical & Electrical Characteristics
Typical Spectrum7
Radiation Pattern7
Thermal Resistance8
Mechanical Dimensions 9
Tape adn Reel Outline 10
Soldering Profile 11
Packaging and shipping specifications 12
Revision History 13

Features:

- High Power UV LED with peak wavelengths 365 nm, 385 nm, 395 nm and 405 nm
- Industry standard 3.5 mm x 3.5 mm package
- 130° viewing angle
- Low Thermal Resistance: 1.4 °C/W
- Built-in ESD Protection
- Environmentally friendly: REACH, RoHS and Halogen compliant

Applications:

- Curing- inks, coating and adhesives
- Photocatalytic air/water purification
- Medical and Analytic instrumentation
- Diagnostics
- Fluorescence Imaging





Technology Overview

Luminus LEDs benefit from innovations in device technology, chip packaging and thermal management. This suite of technologies give engineers and system designers the freedom to develop solutions high both in power and in efficiency.

Luminus Surface Mount LED Technology

Luminus' vertical chip technology enables uniform and high brightness over the entire chip surface.

Thermal management is critical in high power LED applications. With a thermal resistance (R_{th}) from junction to board of 1.4 °C/W, the SST-10 has one of the lowest thermal resistances of UV LEDs in the market. The low R_{th} , along with Luminus vertical chip techology allows users to drive the LEDs at high current densities while maintaining a low junction temperature, thereby resulting in brighter solutions and longer lifetimes.

Reliability

Luminus LEDs are one of the most reliable light sources in the world. They pass a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity, and have been qualified for use in high power and high current applications. Luminus UV LEDs are designed for the most demanding applications with median lifetimes exceeding 30,000 hours.

Environmental Benefits

Luminus LEDs help reduce power consumption and the amount of hazardous waste entering the environment. All Luminus LEDs are RoHS and Halogen compliant and free of hazardous materials, including lead and mercury.



Binning Structure

SST-10-UV LEDs are specified for flux and peak wavelength at a drive current of 500 mA with a 20 ms pulse at 25°C and placed into one of the following Flux Bins and Peak Wavelength Bins.

Flux Bins¹

Color	Power Flux Bin (FF)	Minimum Flux (W)	Maximum Flux (W)
UV	Е	720	810
	F	810	900
	G	900	990
	Н	990	1080
	I	1080	1170

Note 1: Luminus maintains a +/- 6% tolerance on power measurements.

Peak Wavelength Bins

Color	Wavelength Bin (WWW)	Minimum Wavelength (nm)	Maximum Wavelength (nm)
	365	365	370
	370	370	375
	380	380	385
107	385	385	390
UV	390	390	395
	395	395	400
	400	400	405
	405	405	410



Ordering Information

Products	Ordering Part Number	Description
SST-10-UV	SST-10-UV-A130-FFWWW-00 SST-10-UV-B130-FFWWW-00	UV LED in a 3535 surface mount package with a 130 degree molded lens

Part Number Nomenclature

SST —	10 —	UV	 X130	 FFWWW-00

Product Family	Chip Area	Color	Package Configuration ¹	Bin Kit ^{2,3}
SST: Surface Mount package	10: 1 mm²	UV = Ultraviolet	A130 : "A" solder pad layout and 130 ° lens B130 : "B" solder pad layout and 130 ° lens	See ordering bin kits table below for complete bin definition

Note 1: Refer to drawings on page 9 for details on "A" and "B" solder pad layouts

Note 2: A Bin Kit represents a group of flux and wavelength bins that are shippable for a given ordering part number. Individual bins are not orderable..

Note 3: Flux Bin listed is minimum bin shipped - higher bins may be included at Luminus' discretion

Ordering Bin Kits

Ordering	Wavelength Bins	ous Flux		Wavelength Range (nm)	
Bin Kit Number	wavelength bins	Min. Flux (mW)	Bin Kit Flux Code	wavelength hange (fill)	
E365-00	365, 370	720	Е	265 275	
F365-00	365, 375	810	F	365-375	
G385-00	380, 385	380-390 G 900		380-390	
G395-00	390, 395	900	G	390-400	
F405-00	400,405	810	F	400-410	
G3	390, 395	900	G	390-400	



Optical & Electrical Characteristics ($T_{hs} = 25$ °C)

UV						
Parameter	Symbol		Valu	ıes ⁴		Unit
Peak Wavelength Range	λ	365-375	380-390	390-400	400-410	nm
Test Current for binning ⁵	I	500	500	500	500	mA
Peak Wavelength Typ.	$\lambda_{_{p}}$	370	385	395	405	nm
	$V_{_{\rm Fmin}}$	3.0	3.0	3.0	3.0	V
Forward Voltage	$V_{_{\rm F}}$	3.7	3.4	3.3	3.3	V
	V _{F max}	4.0	4.0	4.0	4.0	V
Radiometric Flux ⁶	Φ_{typ}	875	1015	1015	930	mW
FWHM at 50% of Φ	Δλ _{1/2}	10	10	10	10	nm
Viewing Angle	2Φ _{1/2}	130	130	130	130	degrees

Parameter	Symbol	Values
Absolute Maximum Current (CW) 7	 max	365 nm- 1A 385-405 nm- 1.5 A
Maximum Junction Temperature ⁷	T _{jmax}	100 °C
Storage Temperature Range	T _s	-40 to +100 °C
Soldering Temperature	Tsld	JEDEC J-STD-020C, 260 ℃
ESD Sensitivity (HBM)	V _B	6000 V

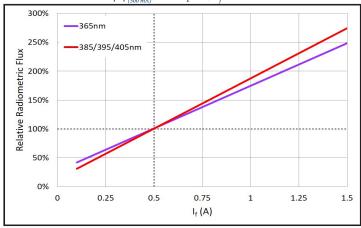
- Note 4: Unless otherwise noted, values listed are typical. Devices are production tested and specified at 500 mA with a 20 ms pulse at 25°C.
- Note 5: While SST-10-UV devices are tested at 500 mA, they can be driven at CW currents ranging from 200 mA to 1.5 A and at duty cycles ranging from 1% to 100%. Drive current and duty cycle should be adjusted as necessary to maintain the junction temperature desired to meet application lifetime requirements.
- Note 6: Typical radiometric flux is for reference only. Minimum flux values are guaranteed based on the bin kit ordered. For product roadmap and future performance of devices, contact Luminus.
- Note 7: SST-10-UV LEDs are designed for operation to an absolute maximum current as specified above. Product lifetime data is specified at or below maximum drive current. Sustained operation beyond absolute maximum currents will result in a reduction of device life time. Actual device lifetimes will also depend on junction temperature and operation beyond maximum junction temperature is not recommended. Contact Luminus for lifetime derating curves and for further information. In pulsed operation, rise time from 10-90% of forward current should be longer than 0.5 µseconds.



Optical & Electrical Characteristics

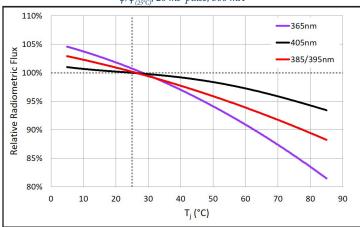
Relative Power vs. Forward Current

 $\varphi/\varphi_{(500 \text{ mA})}$, 20 ms pulse, $T_i = 25$ °C



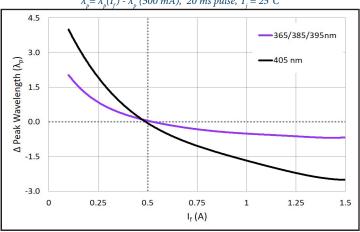
Relative Power vs. Junction Temperature

 $\varphi/\varphi_{(25^{\circ}C)}$, 20 ms pulse, 500 mA



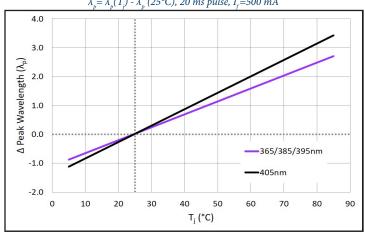
Peak Wavelength Shift vs. Forward Current

 $\lambda_o = \lambda_o(I_f) - \lambda_o$ (500 mA), 20 ms pulse, $T_i = 25$ °C

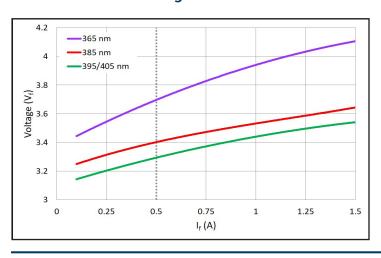


Peak Wavelength Shift vs. Junction Temperature

 $\lambda_{s} = \lambda_{s}(T_{s}) - \lambda_{s}$ (25°C), 20 ms pulse, $I_{s} = 500$ mA

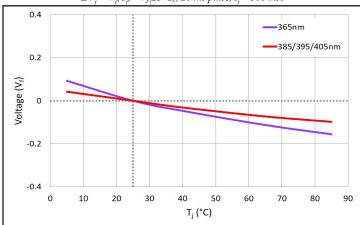


Forward Voltage vs Forward Current



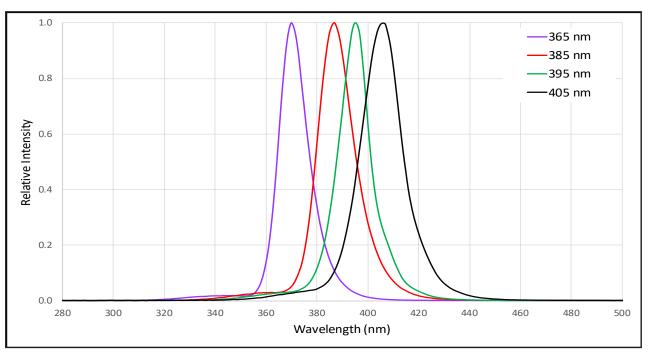
Forward Voltage Shift vs. Junction Temperature

 $\Delta V_{\epsilon} = V_{\epsilon}(T_{\epsilon}) - V_{f,\epsilon}(T_{\epsilon}) - V_{f,\epsilon}(T_{\epsilon}) = 500 \text{ mA}$

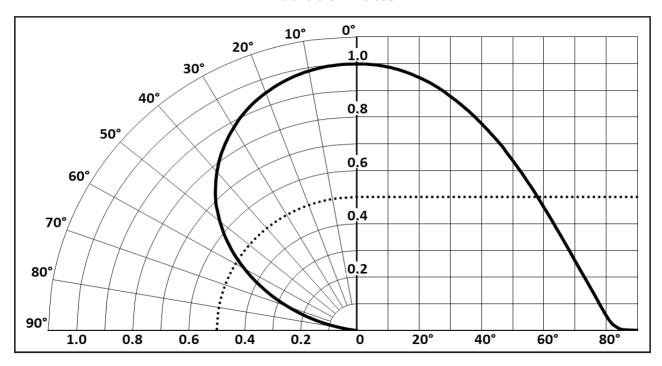




Typical Spectrum⁸



Radiation Pattern⁹

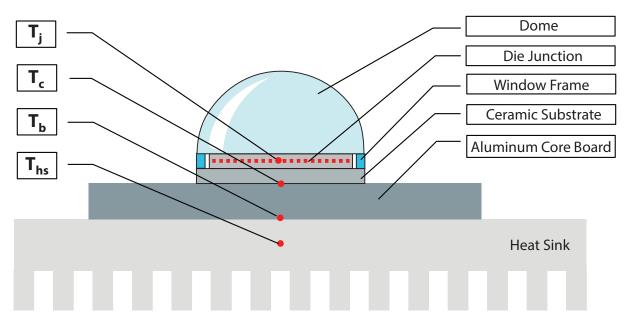


Note 8: Typical spectrum at 500 mA drive current.

Note 9: Detailed information on radiation pattern including ray trace files can be found at: http://www.luminus.com



Thermal Resistance



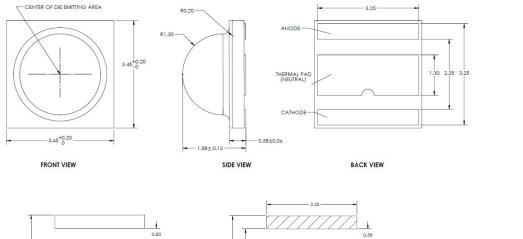
 T_{hs} definition = 3 mm from core-board

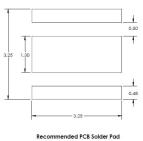
R _{θj-b} ¹⁰ 1.4 °C/W	
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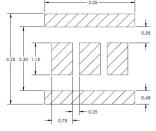
Note 10: Electrical thermal resistance based on input electrical power at 500 mA and measured per JESD51-14



Mechanical Dimensions - A130 package

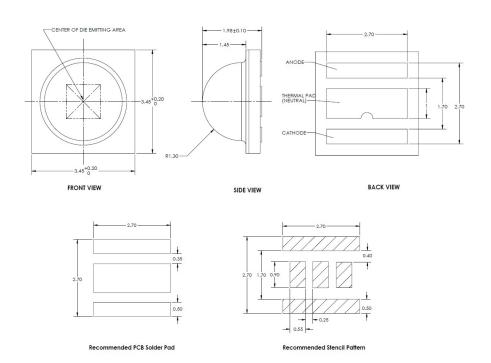






DWG-002848

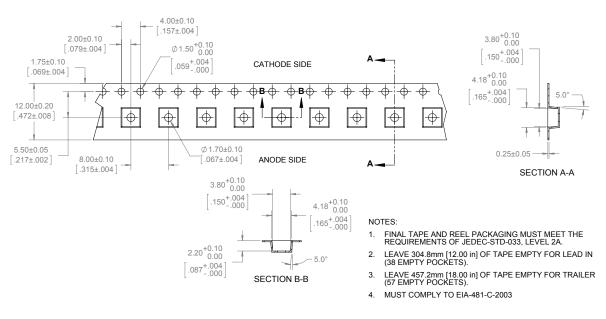
Mechanical Dimensions - B130 package

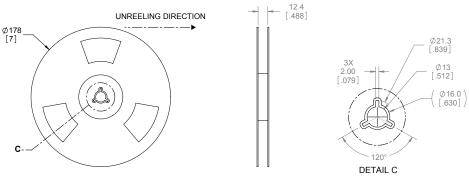


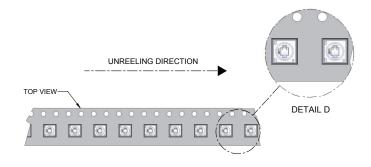
DWG-003005



Tape and Reel Outline







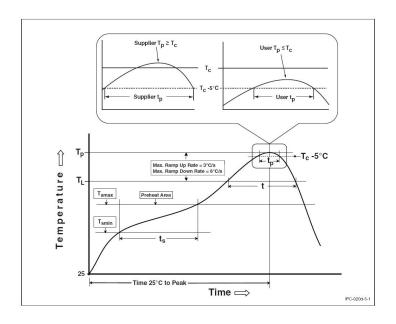


Soldering Profile

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak Temperature min (Tsmin) Temperature max (Tsmax) Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-120 seconds
Average ramp-up rate (Tsmax to Tp) Liquidous temperature (TL) Time at liquidous (tL)	3 °C/second max 183 °C 60-150 seconds	3 °C/second max 217 °C 60-150 seconds
Peak package body temperature (Tp)* Classification temperature (Tc)	230 °C ~235 °C 235 °C	255 °C ~260 °C 260 °C
Time (tp) within 5 °C of the specified classification temperature (Tc) Average ramp-down rate (Tp to Tsmax)	20 seconds 6 °C/second max	30 seconds 6 °C/second max
Time 25 °C to peak temperature	6 minutes max	8 minutes max

^{*} Tolerance for peak profile temperature(Tp) is defined as a supplier minimum and a user maximum.

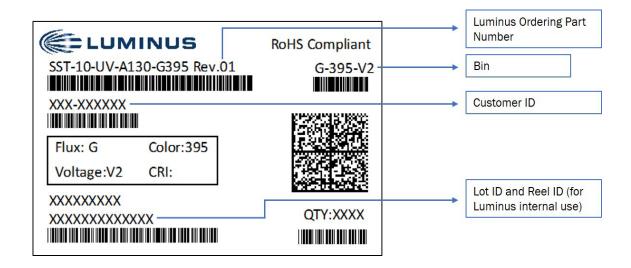
^{**} Tolerance for time at peak profile temperature(tp) is defined as asupplier minimum and a user maximum.





Packing and Shipping Specifications

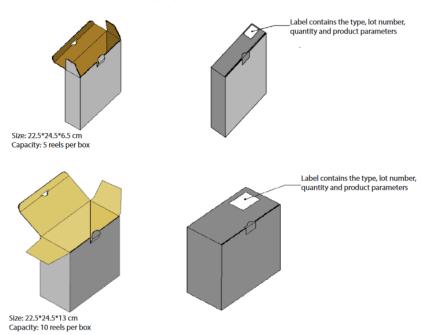
Product Label Specification



Sample label –for illustration only

Shipping Box

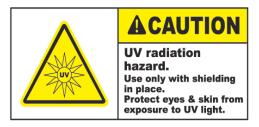
Box Packaging Information





Revision History

Rev	Date	Description of Change
01	06/01/2018	Initial Release
02	8/31/12018	Added "B130" version: updated ordering part numbers, characterization graphs and mechanical drawings



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